SN55ALS195, SN75ALS195 QUADRUPLE DIFFERENTIAL LINE RECEIVERS

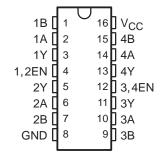
SLLS010D - JUNE 1986 - REVISED MAY 1995

- Meet or Exceed the Requirements of ANSI Standards EIA/TIA-422-B and EIA/TIA-423-A
- Meet ITU Recommendations V.10 and V.11
- Designed to Operate Up to 20 Mbaud
- • -7 V to 7 V Common-Mode Input Voltage Range With 200-mV Sensitivity
- 3-State TTL-Compatible Outputs
- High Input Impedance . . . 12 k Ω Min
- Input Hysteresis . . . 120 mV Typ
- Single 5-V Supply Operation
- Low Supply Current Requirement 35 mA Max
- Improved Speed and Power Consumption Compared to MC3486

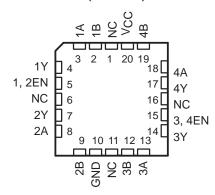
description

The SN55ALS195 and SN75ALS195 are four differential line receivers with 3-state outputs designed using advanced low-power Schottky technology. This technology provides combined improvements in die design, tooling production, and wafer fabrication, which in turn, provide lower power consumption and permit much higher data throughput than other designs. The devices meet the specifications of ANSI Standards EIA/TIA-422-B and EIA/TIA-423-A and ITU Recommendations V.10 and V.11. The 3-state outputs permit direct connection to a bus-organized system with a fail-safe design that ensures the outputs will always be high if the inputs are open.

SN55ALS195 ... J OR W PACKAGE SN75ALS195 ... J OR N PACKAGE[†] (TOP VIEW)



SN55ALS195...FK PACKAGE (TOP VIEW)



NC – No internal connection † For surface-mount package, see the SN75ALS199.

The devices are optimized for balanced multipoint bus transmission at rates up to 20 megabits per second. The input features high input impedance, input hysteresis for increased noise immunity, and an input sensitivity of ± 200 mV over a common-mode input voltage range of ± 7 V. The devices also feature an active-high enable function for each of two receiver pairs. The SN55ALS195 and SN75ALS195 are designed for optimum performance when used with the SN55ALS194 and SN75ALS194 quadruple differential line drivers.

The SN55ALS195 is characterized for operation over the full military temperature range of -55° C to 125°C. The SN75ALS195 is characterized for operation from 0°C to 70°C.



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SN55ALS195, SN75ALS195 QUADRUPLE DIFFERENTIAL LINE RECEIVERS

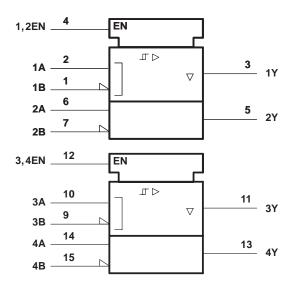
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FUNCTION TABLE (each receiver)

| DIFFERENTIAL INPUTS A-B | ENABLE EN | OUTPUT Y |
|---|--------------|-------------|
| V _{ID} ≥ 0.2 V | Н | Н |
| $-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$ | Н | ? |
| $V_{1D} \le -0.2 V$ | Н | L |
| X | L | Z |
| Open | Н | Н |

H = high level, L = low level, X = irrelevant, ? = indeterminate,

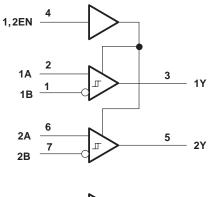
logic symbol†

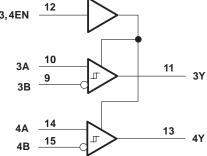


[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the J, N, and W packages.

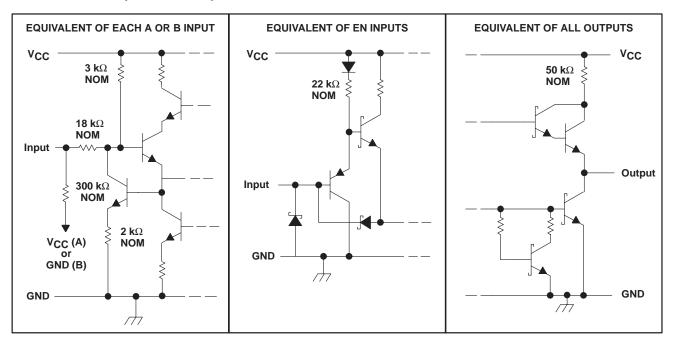
logic diagram





Z = high impedance (off)

schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage, V _{CC} (see Note 1) | 7 V |
|---|------------------------------|
| Input voltage, A or B inputs, V _I | ±15 V |
| Differential input voltage, V _{ID} (see Note 2) | ±15 V |
| Enable input voltage, V _I | |
| Low-level output current, I _{OI} | 50 mA |
| Continuous total dissipation | See Dissipation Rating Table |
| Operating free-air temperature range, T _A : SN55ALS195 | – 55°C to 125°C |
| SN75ALS195 | 0°C to 70°C |
| Storage temperature range, T _{stq} | – 65°C to 150°C |
| Case temperature for 60 seconds, T _C : FK package | |
| Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J, N, or W pa | |

[†] Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential input voltage, are with respect to network ground terminal.

2. Differential-input voltage is measured at the noninverting input with respect to the corresponding inverting input.

DISSIPATION RATING TABLE

| PACKAGE | $T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING | DERATING FACTOR ABOVE T _A = 25°C | T _A = 70°C POWER RATING | T _A = 125°C POWER RATING |
|----------------|--|--|---------------------------------------|--|
| FK | 1375 mW | 11.0 mW/°C | 880 mW | 275 mW |
| J (SN55ALS195) | 1375 mW | 11.0 mW/°C | 880 mW | 275 mW |
| J (SN75ALS195) | 1025 mW | 8.2 mW/°C | 656 mW | N/A |
| N | 1150 mW | 9.2 mW°C | 736 mW | N/A |
| W | 1000 mW | 8.0 mW/°C | 640 mW | 200 mW |



SN55ALS195, SN75ALS195 QUADRUPLE DIFFERENTIAL LINE RECEIVERS

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recommended operating conditions

| | SN55ALS195 | | SN75ALS195 | | | UNIT | |
|---|------------|-----|------------|------|-----|------|------|
| | MIN | NOM | MAX | MIN | NOM | MAX | UNIT |
| Supply voltage, V _{CC} | 4.5 | 5 | 5.5 | 4.75 | 5 | 5.25 | V |
| Common-mode input voltage, V _{IC} | | | ±7 | | | ±7 | V |
| Differential input voltage, V _{ID} | | | ±12 | | | ±12 | V |
| High-level input voltage, VIH | 2 | | | 2 | | | V |
| Low-level input voltage, V _{IL} | | | 0.8 | | | 0.8 | V |
| High-level output current, IOH | | | -400 | | | -400 | μΑ |
| Low-level output current, IOL | | | 16 | | | 16 | mA |
| Operating free-air temperature, TA | -55 | | 125 | 0 | | 70 | °C |

electrical characteristics over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

| PARAMETER | TEST CONDITIONS† | | MIN | TYP‡ | MAX | UNIT | |
|---|--|--|---|---|---|---|--|
| Positive-going input threshold voltage | | | | | | 200 | mV |
| Negative-going input threshold voltage | | | | -200§ | | | mV |
| Hysteresis voltage (V _{IT+} – V _{IT-}) | | | | | 120 | | mV |
| Enable-input clamp voltage | V _{CC} = MIN, | $I_{ } = -18 \text{ mA}$ | | | | -1.5 | V |
| High-level output voltage | V _{CC} = MIN, See Figure 1 | V _{ID} = 200 mV, | $I_{OH} = -400 \mu A$, | 2.5 | 3.6 | | V |
| Low lovel output voltage | V _{CC} = MIN, | I _{OL} = 8 mA | | | | 0.45 | V |
| Low-level output voltage | See Figure 1 | I _{OL} = 16 mA | | | | 0.5 | V |
| High-impedance-state | V _{CC} = MAX, V _O = 2.7 V | V _{IL} = 0.8 V, | $V_{ID} = -3 V$, | | | 20 | 4 |
| OZ output current | V _{CC} = MAX, V _O = 0.5 V | V _{IL} = 0.8 V, | V _{ID} = 3 V, | | | -20 | μΑ |
| Line input current | Other input at 0 V, | V _{CC} = MIN, | V _I = 15 V | | 0.7 | 1.2 | m A |
| Line input current | See Note 3 | $V_{CC} = MAX,$ | V _I = −15 V | | -1 | -1.7 | mA |
| High lovel enable input ourrent | V00 - MAY | V _{IH} = 2.7 V V _{IH} = 5.25 V | | | 20 | | |
| nign-ievei enable-input current | ACC = INIXX | | | | | 100 | μΑ |
| Low-level enable-input current | $V_{CC} = MAX$, | V _{IL} = 0.4 V | | | | -100 | μΑ |
| Input resistance | | | | 12 | 18 | | kΩ |
| Short-circuit output current | V _{CC} = MAX, See Note 4 | V _{ID} = 3 V, | V _O = 0, | -15 | -78 | -130 | mA |
| Supply current | V _{CC} = MAX, | Outputs disabled | | | 22 | 35 | mA |
| | Positive-going input threshold voltage Negative-going input threshold voltage Hysteresis voltage (V _{IT+} - V _{IT-}) Enable-input clamp voltage High-level output voltage Low-level output voltage High-impedance-state output current Line input current High-level enable-input current Low-level enable-input current Input resistance Short-circuit output current | Positive-going input threshold voltage Negative-going input threshold voltage Hysteresis voltage (V _{IT+} - V _{IT-}) Enable-input clamp voltage V _{CC} = MIN, See Figure 1 V _{CC} = MIN, See Figure 1 V _{CC} = MIN, See Figure 1 V _{CC} = MAX, V _{ID} = -200 mV, See Figure 1 V _{CC} = MAX, V _O = 2.7 V V _{CC} = MAX, V _O = 0.5 V Line input current Cher input at 0 V, See Note 3 High-level enable-input current V _{CC} = MAX See Note 3 | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ |

[†] For conditions shown as MIN or MAX, use the appropriate values specified under recommended operating conditions. ‡ All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[§] The algebraic convention, in which the less positive limit is designated minimum, is used in this data sheet for threshold voltage levels only.

NOTES: 3. Refer to ANSI Standards EIA/TIA-422-B and EIA/TIA-423-A for exact conditions.

^{4.} Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C

| PARAMETER T | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|---|--|-----|-----|-----|------|
| tPLH | Propagation delay time, low- to high-level output | V _{ID} = 0 to 3 V, See Figure 2 | | 15 | 22 | ns |
| tPHL | Propagation delay time, high- to low-level output | VID = 0 to 5 V, See Figure 2 | | 15 | 22 | ns |
| ^t PZH | Output enable time to high level | See Figure 3 | | 13 | 25 | ns |
| tPZL | Output enable time to low level | See Figure 3 | | 10 | 25 | 115 |
| tPHZ | Output disable time from high level | See Figure 3 | | 19 | 25 | no |
| t _{PLZ} | Output disable time from low level | See Figure 3 | | 17 | 22 | ns |

PARAMETER MEASUREMENT INFORMATION

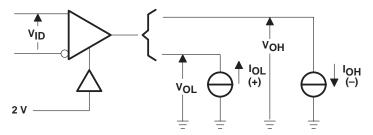
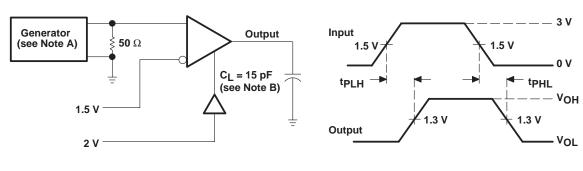


Figure 1. V_{OH}, V_{OL}

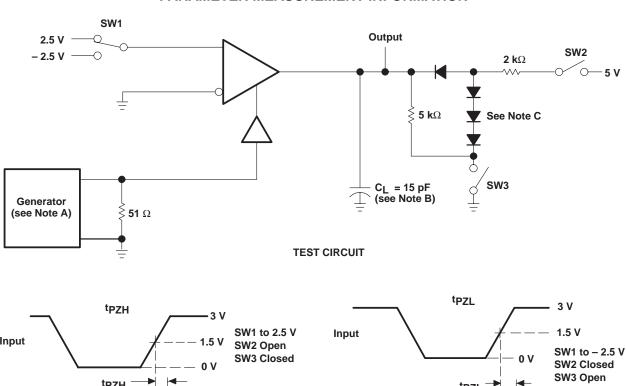


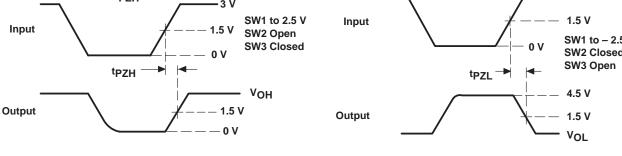
TEST CIRCUIT VOLTAGE WAVEFORMS

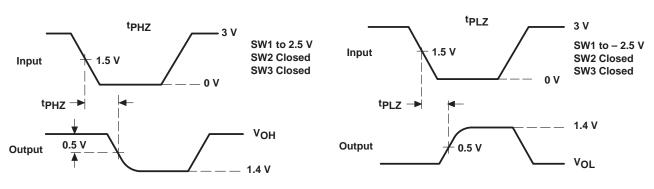
- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, $Z_O =$ 50 Ω , $t_f \leq$ 6 ns, $t_f \leq$ 6 ns.
 - B. C_L includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION







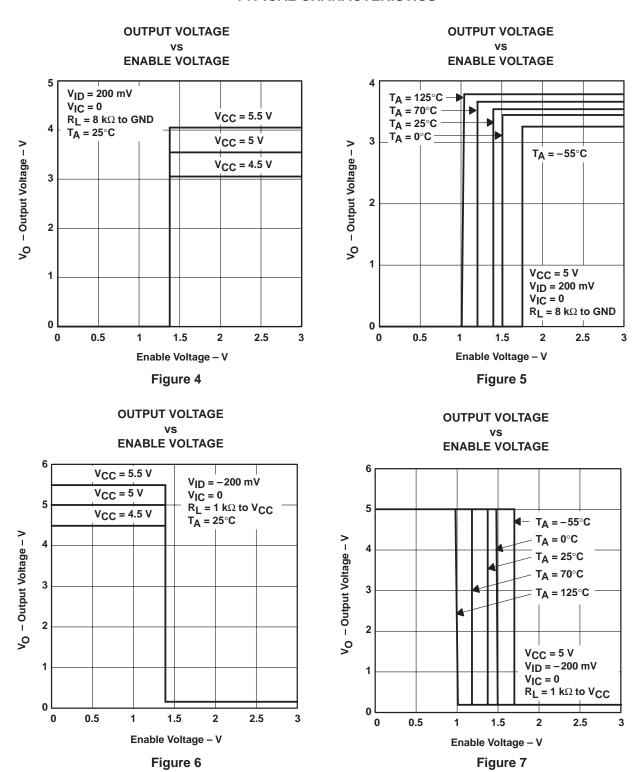
VOLTAGE WAVEFORMS

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, Z_O = 50 Ω , $t_{\Gamma} \le 6$ ns, $t_{f} \le 6$ ns. B. C_L includes probe and jig capacitance. C. All diodes are 1N3064 or equivalent.

Figure 3. Test Circuit and Voltage Waveforms



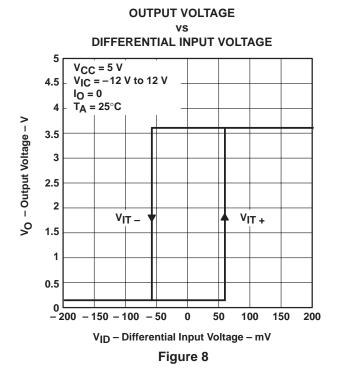
TYPICAL CHARACTERISTICS†

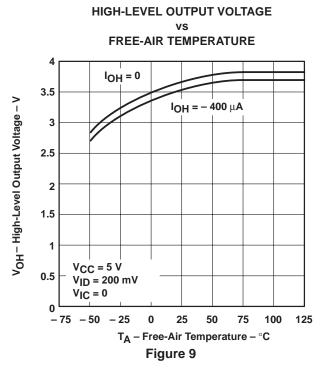


[†] Data for temperatures below 0°C and above 70°C, and below 4.75 V and above 5.25 V, are applicable to SN55ALS195 circuits only.

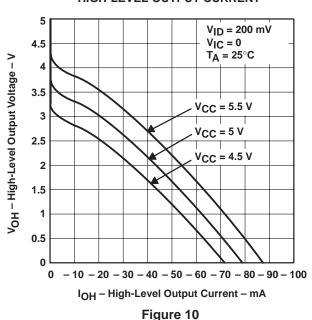


TYPICAL CHARACTERISTICS[†]

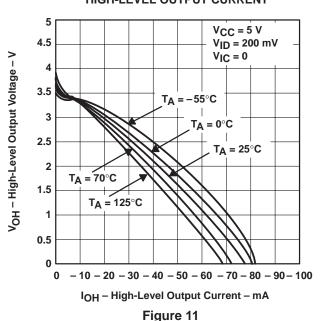




HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT



HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT



[†] Data for temperatures below 0°C and above 70°C, and below 4.75 V and above 5.25 V, are applicable to SN55ALS195 circuits only.



TYPICAL CHARACTERISTICS[†]

LOW-LEVEL OUTPUT VOLTAGE vs FREE-AIR TEMPERATURE

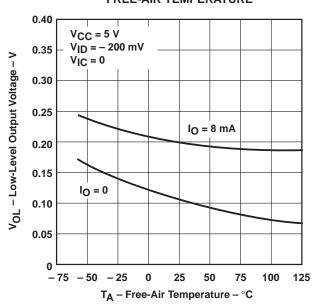
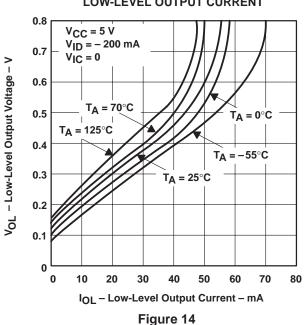


Figure 12

LOW-LEVEL OUTPUT VOLTAGE LOW-LEVEL OUTPUT CURRENT 0.8 0.7 V_{OL} - Low-Level Output Voltage - V V_{CC} = 4.5 V V_{CC} = 5 V 0.6 V_{CC} = 5.5 V 0.5 0.4 0.3 0.2 $V_{ID} = -200 \text{ mV}$ 0.1 $V_{IC} = 0$ T_A = 25°C 0 0 10 20 30 40 50 70 80 IOL - Low-Level Output Current - mA

Figure 13

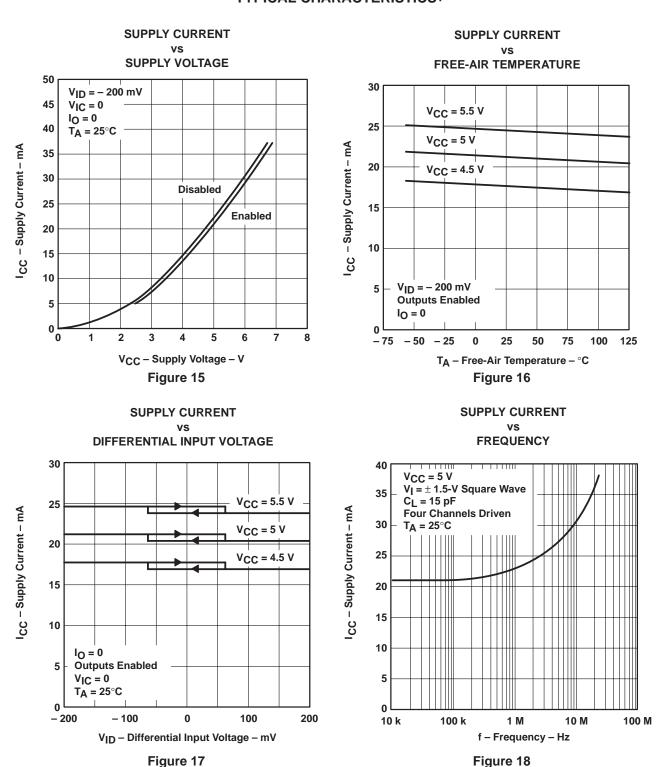
LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT



† Data for temperatures below 0°C and above 70°C, and below 4.75 V and above 5.25 V, are applicable to SN55ALS195 circuits only.



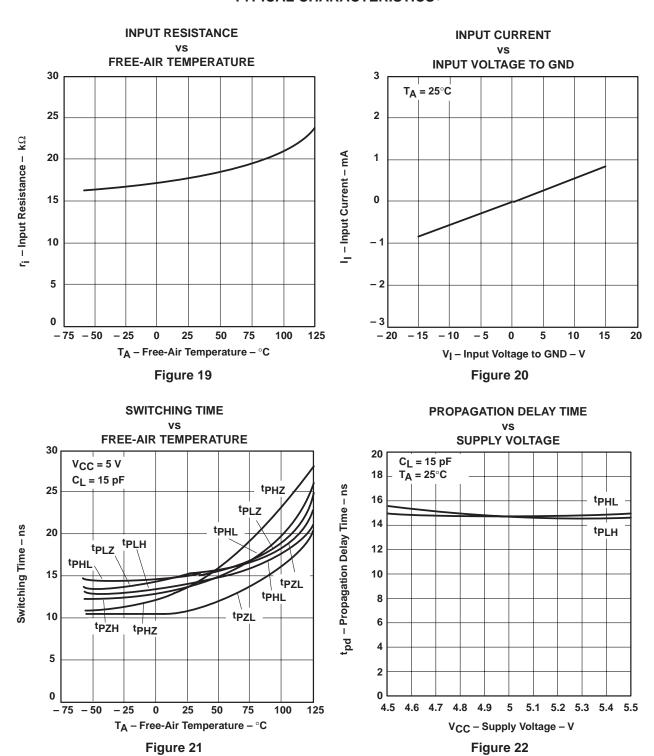
TYPICAL CHARACTERISTICS†



† Data for temperatures below 0°C and above 70°C, and below 4.75 V and above 5.25 V, are applicable to SN55ALS195 circuits only.



TYPICAL CHARACTERISTICS†



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